Ground Fault Circuit Interrupter

Description

The KA2807 is an IC for ground fault circuit interrupters which are intended to provide an electrical shock hazard protection from line to ground fault currents on grounded circuits of 120 V supplies.

Features

- Full Advantage of the UL943
- Built-In Voltage Regulator
- Sense Coil Ratio 1000:1
- GND/Neutral Coil Ratio 200:1
- Trip Time in Normal Fault and Grounded Neutral Fault is 18 ms Typ
- Wide Operating Temperature Range
- Excellent ESD Characteristic
- 1 mA Output Current Pulse to Trigger SCR
- Available in 8 Pin SOIC and 8 Pin MSOP
- Pb-Free Device



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RELATED STANDARDS

UL943

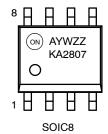


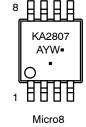




Micro8 CASE 846A

MARKING DIAGRAMS





KA2807 = Specific Device Code A = Assembly Location

Y = Year
W = Work Week
ZZ = Assembly LOT Code
■ Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping [†]
KA2807DTF	SOIC (Pb-Free)	2,500 / Tape & Reel
KA2807MUX	Micro8 (Pb-Free)	4,000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

PIN ASSIGNMENT

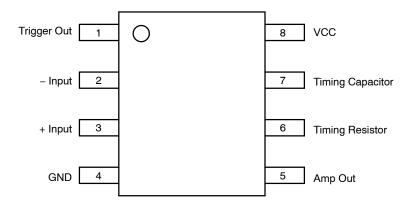


Figure 1. Pin Out KA2807 in 8-pin SOP or MSOP (Top View)

BLOCK DIAGRAM

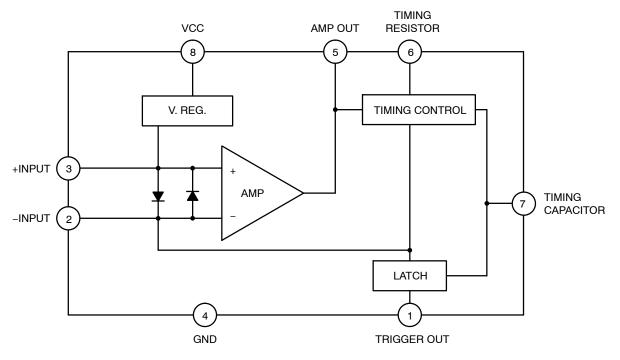


Figure 2. KA2807 Block Diagram

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Min	Max	Unit
I _{CC}	Supply Current	-	+19	mA
P _D	Power Dissipation SOIC-8 MSOP-8	- -	0.41 0.3	W
T _{OPR}	Operating Temperature Range	-40	+70	°C
T _{STG}	Storage Temperature Range	-55	+150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{REG}	Shunt Regulator Voltage	Pin 8, S1: 2, S2: OFF	23	26	29	V
V_{REF}	Amplifier Reference Voltage	Pin 3, S1: 2, S2: OFF	9.5	10.5	11.5	V
V _{OH}	Amplifier High Output Voltage	Pin 5, S1: 3, S2: ON Sig: 800 Hz, 3.0 V _{P-P} Sinusoidal wave	17	19	21	V
V _{OL}	Amplifier Low Output Voltage	Pin 5, S1: 3, S2: ON Sig: 800 Hz, 3.0 V _{P-P} Sinusoidal wave	1.5	2.5	3.5	V
I _{SEN}	Amplifier Sensitivity Current	Pin 2, S1: 3, S2: ON Sig: 800 Hz, 1.0 V _{P-P} ~ 2.5 V _{P-P} Sinusoidal wave	3.5	5	6.5	μArms
V _{ON(LATCH)}	Latch On Voltage	Pin 7, S1: 3, S2: ON Sig: 800 Hz, 3.0 V _{P-P} Sinusoidal wave	16.5	17.5	19.5	V
I _{TR}	SCR Trigger Current	Pin 1, S1: 3, S2: ON Sig: 800 Hz, 3.0 V _{P-P} Sinusoidal wave	0.5	1	2.0	mA
V _S 1	Output Low Voltage	Pin 1, S1: 2, S2: OFF		100	240	mA
Z _O	Output Impedance	Pin 1, S1: 2, S2: OFF	_	100	250	Ω
I _{SINK}	Output Sink Current	Pin 1, S1: 2, S2: OFF	2.0	6.0	-	mA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

TEST CIRCUIT

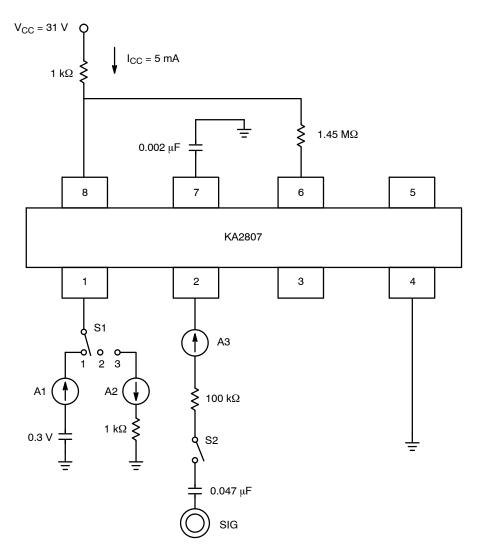
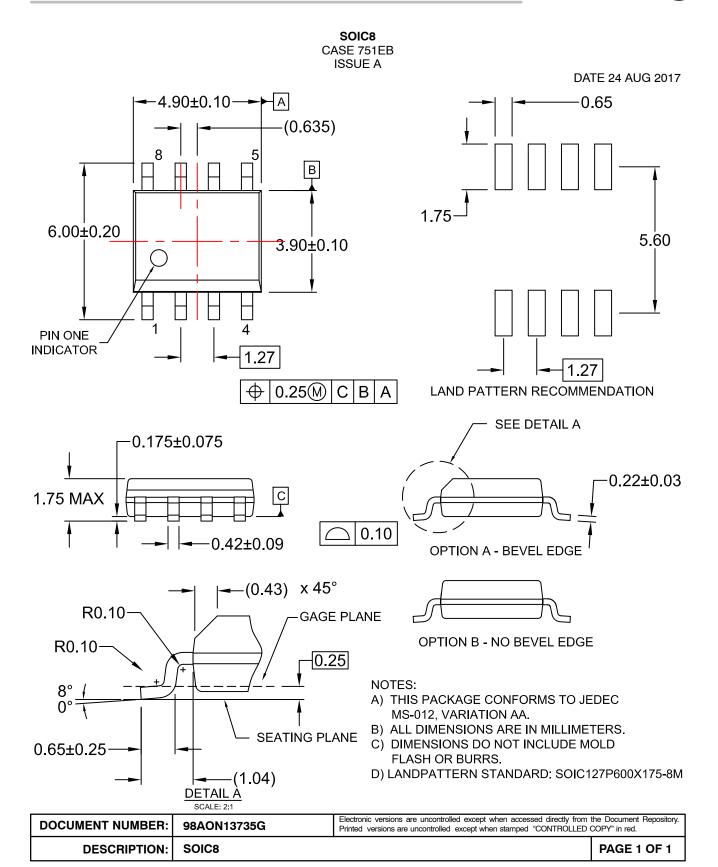


Figure 3. KA2807 Test Circuit

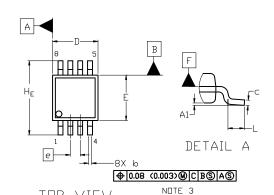


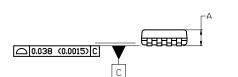
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Micro8 CASE 846A-02 ISSUE K

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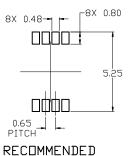




DETAIL A

NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2009.
- CONTROLLING DIMENSION: MILLIMETERS
- DIMENSION 6 DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.10 mm IN EXCESS OF MAXIMUM MATERIAL CONDITION.
- DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSION OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.15 mm PER SIDE. DIMENSION E DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 mm PER SIDE. DIMENSIONS D AND E ARE DETERMINED AT DATUM F.
- DATUMS A AND B ARE TO BE DETERMINED AT DATUM F.
- A1 IS DEFINED AS THE VERTICAL DISTANCE FROM THE SEATING PLANE TO THE LOWEST POINT ON THE PACKAGE BODY.



MOUNTING FOOTPRINT

DIM	MILLIMETERS			
INITI	MIN.	N□M.	MAX.	
Α	-	-	1.10	
A1	0.05	0.08	0.15	
b	0.25	0.33	0.40	
c	0.13	0.18	0.23	
D	2.90	3.00	3.10	
Е	2.90	3.00	3.10	
е	0.65 BSC			
HE	4.75	4.90	5.05	
L	0.40	0.55	0.70	

GENERIC MARKING DIAGRAM*

SIDE VIEW

TOP VIEW



XXXX = Specific Device Code Α = Assembly Location

Υ = Year W = Work Week = Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

STYLE 1:	STYLE 2:	STYLE 3:
PIN 1. SOURCE	PIN 1. SOURCE 1	PIN 1. N-SOURCE
SOURCE	2. GATE 1	2. N-GATE
SOURCE	3. SOURCE 2	3. P-SOURCE
GATE	4. GATE 2	4. P-GATE
DRAIN	5. DRAIN 2	5. P-DRAIN
DRAIN	6. DRAIN 2	6. P-DRAIN
7. DRAIN	7. DRAIN 1	7. N-DRAIN
8. DRAIN	8. DRAIN 1	8. N-DRAIN

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